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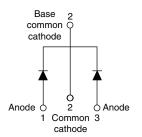


VS-16CTQ...PbF Series, VS-16CTQ...-N3 Series

Vishay Semiconductors

Schottky Rectifier, 2 x 8 A



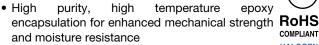


TO-220AB

PRODUCT SUMMARY				
Package	TO-220AB			
I _{F(AV)}	2 x 8 A			
V_{R}	60 V, 80 V, 100 V			
V _F at I _F	0.58 V			
I _{RM} max.	7 mA at 125 °C			
T _J max.	175 °C			
Diode variation	Common cathode			
E _{AS}	7.5 mJ			

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long FREE term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL CHARACTERISTICS VALUES UNITS						
I _{F(AV)}	Rectangular waveform	16	А			
V_{RRM}		60 to 100	V			
I _{FSM}	t _p = 5 μs sine	850	А			
V _F	8 A _{pk} , T _J = 125 °C (per leg)	0.58	V			
T_J	Range	- 55 to 175	°C			

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS- 16CTQ060PbF	VS- 16CTQ060-N3	VS- 16CTQ080PbF	VS- 16CTQ080-N3	VS- 16CTQ100PbF	VS- 16CTQ100-N3	UNITS
Maximum DC reverse voltage	V _R							
Maximum working peak reverse voltage	V _{RWM}	60	60	80	80	100	100	V

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	per leg		$I_{E/\Delta M}$ 50 % duty cycle at T_C = 148 °C, rectangular waveform		8	Α
See fig. 5	per device	I _{F(AV)}	50 % duty cycle at 1 _C = 146 °C	16	^	
Maximum peak one cycle non-repetitive		I	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	850	Α
surge current per leg See fig. 7		I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	275	A
Non-repetitive avalanche ene	rgy per leg	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 0.50 \text{A}, L = 60 \text{C}$) mH	7.50	mJ



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ABSOLUTE MAXIMUM RATINGS							
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical	0.50	Α			

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
Maximum forward voltage drop per leg See fig. 1		8 A	T _{.1} = 25 °C	0.72	V	
	V _{FM} ⁽¹⁾	16 A	1j=25 C	0.88		
	V _{FM} (1)	8 A	T 105 °C	0.58		
		16 A	T _J = 125 °C	0.69		
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V = rotad V	0.55	mA	
See fig. 2	IRM (")	T _J = 125 °C	V _R = rated V _R	7.0		
Threshold voltage	V _{F(TO)}	T T maximum		0.415	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum		11.07	mΩ	
Maximum junction capacitance per leg	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		500	pF	
Typical series inductance per leg	L _S	Measured lead to lead 5 m	8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/μs	

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55 to 175	°C			
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	3.25	°C/W			
Maximum thermal resistance junction to case per package	R _{thJC}	DC operation	1.63				
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50				
Approximate weight			2	g			
Approximate weight			0.07	OZ.			
Marinting to some			6 (5)	kgf · cm			
Mounting torque maximum			12 (10)	(lbf · in)			
			16CTQ060				
Marking device		Case style TO-220AB	16CTQ080				
			16CTQ100				

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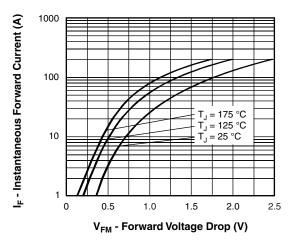


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

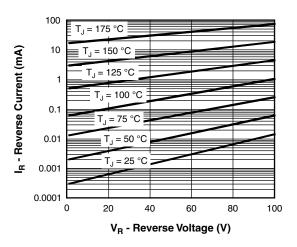


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

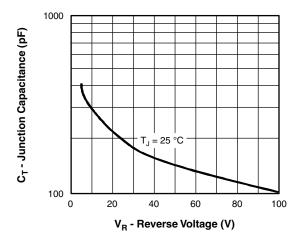


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

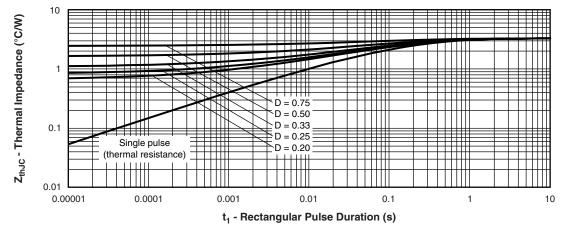


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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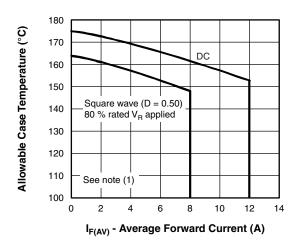


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

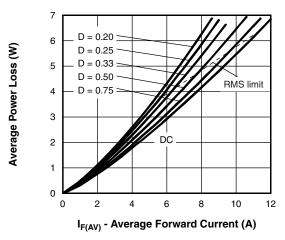


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

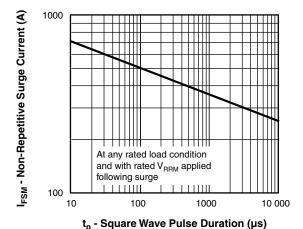


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

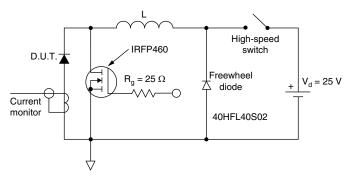


Fig. 8 - Unclamped Inductive Test Circuit

Note

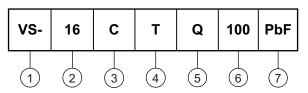
 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R applied

VS-16CTQ...PbF Series, VS-16CTQ...-N3 Series

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (16 = 16 A)

3 - Circuit configuration

C = Common cathode

4 - Package

T = TO-220

5 - Schottky "Q" series

060 = 60 V 080 = 80 V

6 - Voltage rating

100 = 100 V

7 - Environmental digit

- PbF = Lead (Pb)-free and RoHS compliant
- -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-16CTQ060PbF	50	1000	Antistatic plastic tube				
VS-16CTQ060-N3	50	1000	Antistatic plastic tube				
VS-16CTQ080PbF	50	1000	Antistatic plastic tube				
VS-16CTQ080-N3	50	1000	Antistatic plastic tube				
VS-16CTQ100PbF	50	1000	Antistatic plastic tube				
VS-16CTQ100-N3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95222</u>					
Pod and in the matter	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			
SPICE model		www.vishay.com/doc?95279			



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead assignments

Diodes

- 1. Anode/open
- 2. Cathode
- 3. Anode

Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	AROL MILLIMETERS INCHES		NOTES		
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	
		•	•	•	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip



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